

**SCHOTTKY BARRIER RECTIFIERS**

**APD260**

**Features**

- Low Forward Voltage Drop
- Very Small Conduction Losses
- High Surge Capability
- Surge Overload Rating up to 50A Peak Value

**Applications**

- Low Voltage High Frequency Inverters
- DC-DC Converters
- Free Wheeling
- Polarity Protection

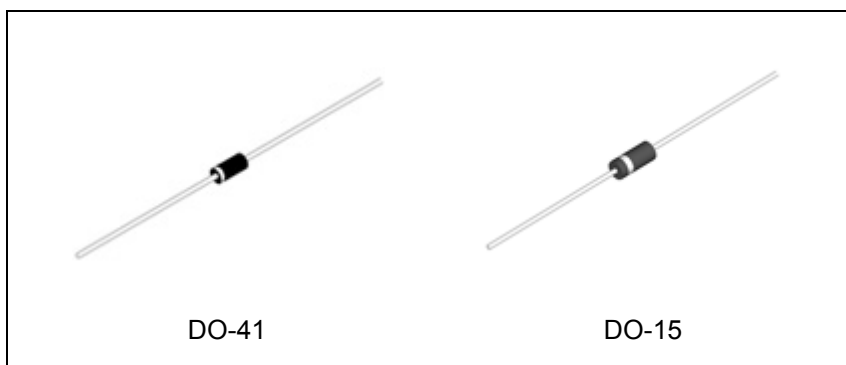


Figure 1. Package Types of APD260

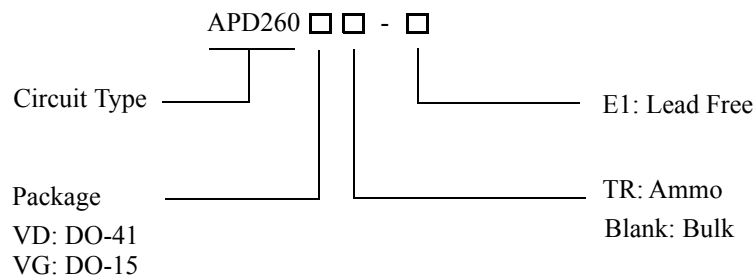
**Pin Configuration**

VD/VG Package

(DO-41/DO-15)



Figure 2. Pin Configuration of APD260

**SCHOTTKY BARRIER RECTIFIERS****APD260****Ordering Information**

Package	Part Number	Marking ID	Packing Type
DO-41	APD260VD-E1	D260VD	Bulk
	APD260VDTR-E1	D260VD	Ammo
DO-15	APD260VG-E1	D260VG	Bulk
	APD260VGTR-E1	D260VG	Ammo

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**Absolute Maximum Ratings** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted) (Note 1)

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	60	V
Maximum DC Blocking Voltage	$V_{DC}$	60	V
Maximum RMS Voltage	$V_{RMS}$	42	V
Average Rectified Forward Current 0.375 " (9.5mm) Lead Length (See Figure 3)	$I_{F(AV)}$	2.0	A
Non-Repetitive Peak Forward Surge Current 8.3 ms Single Half Sine-Wave on Rated Load	$I_{FSM}$	50	A
Operating Junction Temperature Range	$T_J$	-65 to 125	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to 150	$^{\circ}\text{C}$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.



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**APD260**

**Thermal Characteristics** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Values	Unit
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	52	$^{\circ}\text{C}/\text{W}$
	$R_{\theta JL}$	14	

Note 2: Thermal resistance from junction to lead, PCB mounted, 0.375" (9.5mm) lead length.

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Values	Unit
Forward Voltage @ $I_F=2.0\text{A}$	$V_F$	0.68	V
Reverse Current @ Rated $V_R$ (Note 3)	$I_R$	$T_A=25^{\circ}\text{C}$	0.5
		$T_A=100^{\circ}\text{C}$	10

Note 3: Pulse Test: 300  $\mu\text{s}$  pulse width, 1.0% duty cycle.

**Typical Performance Characteristics** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

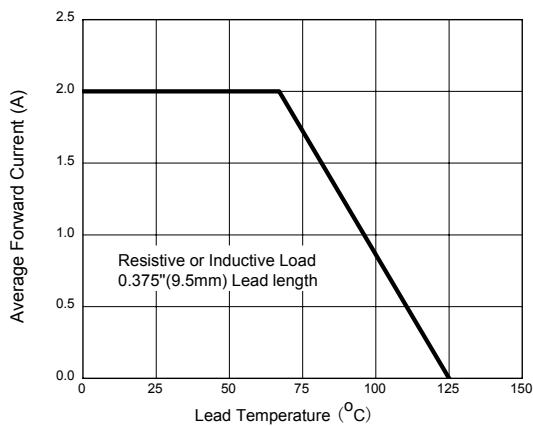


Figure 3. Forward Current Derating Curve

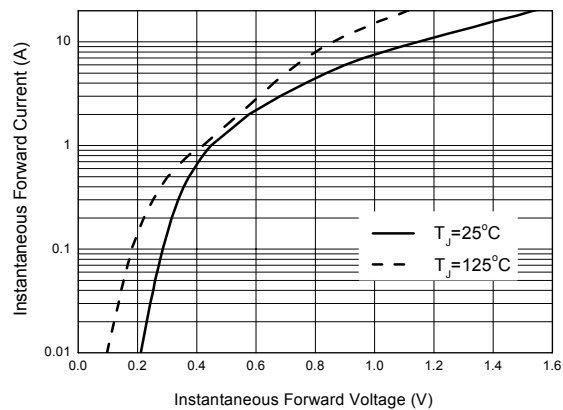


Figure 4. Typical Instantaneous Forward Characteristics



Typical Performance Characteristics (Continued)

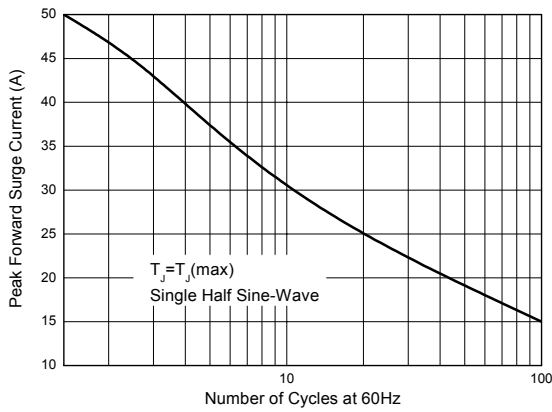


Figure 5. Maximum Non-Repetitive Peak Forward Surge Current

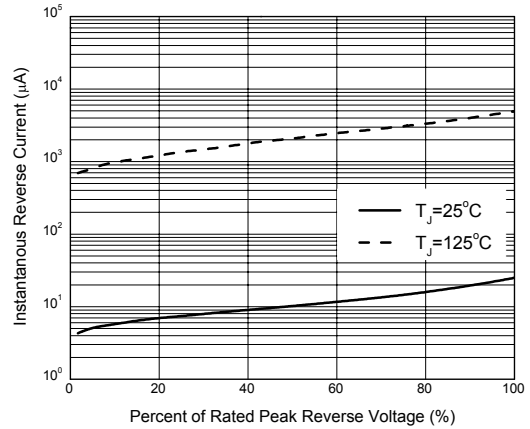


Figure 6. Typical Reverse Characteristics

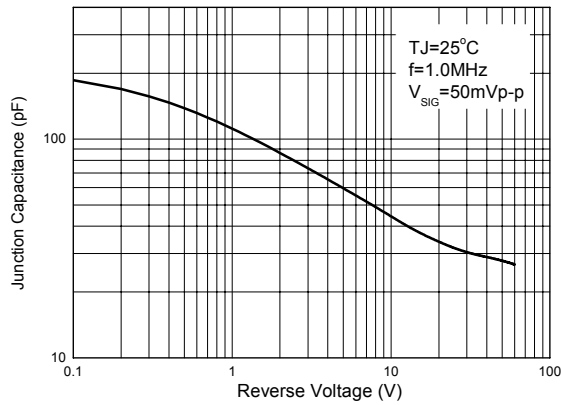


Figure 7. Typical Junction Capacitance



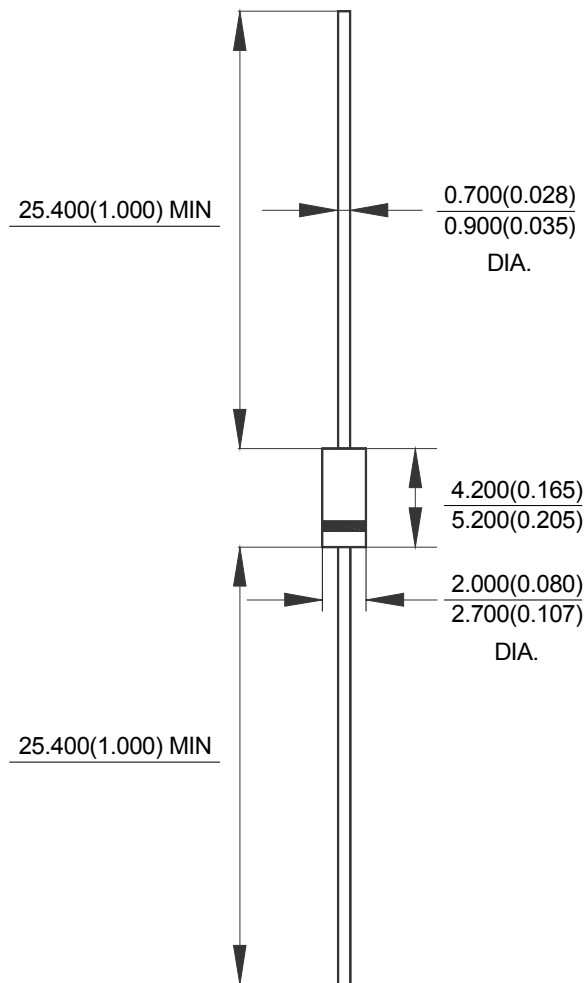
**SCHOTTKY BARRIER RECTIFIERS**

**APD260**

**Mechanical Dimensions**

**DO-41**

**Unit: mm(inch)**





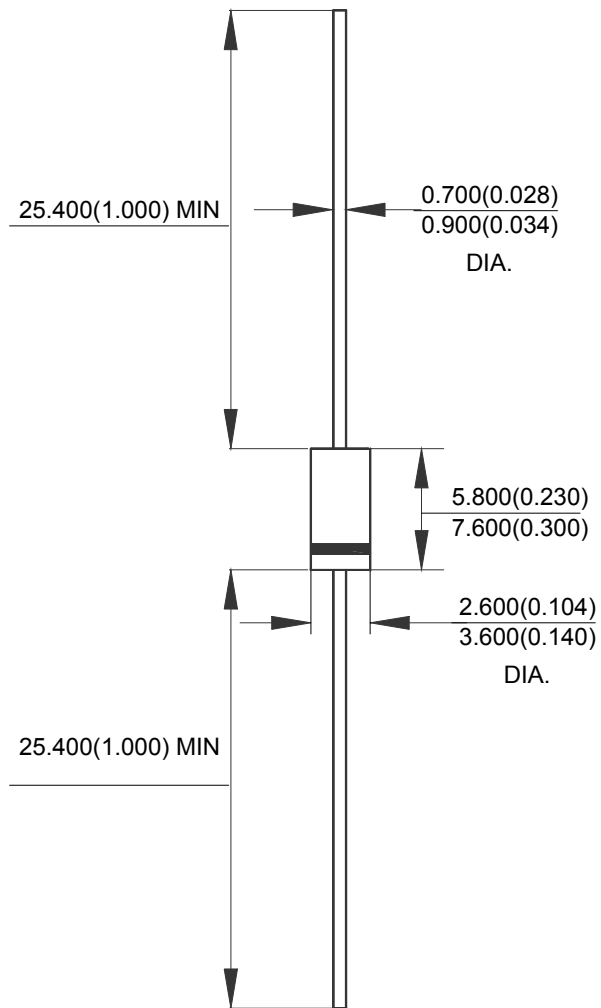
**SCHOTTKY BARRIER RECTIFIERS**

**APD260**

**Mechanical Dimensions (Continued)**

**DO-15**

**Unit: mm(inch)**





## **BCD Semiconductor Manufacturing Limited**

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